onsemi

Dual 2-Input Exclusive-OR MARKING DIAGRAMS Gate 8888 **NL27WZ86** XXXX US8 The NL27WZ86 is a high performance dual 2-input Exclusive-OR ALYW **US SUFFIX** Gate operating from a 1.65 V to 5.5 V supply. O **CASE 493** Features Commercial • Designed for 1.65 V to 5.5 V V_{CC} Operation 8888 • 2.9 ns t_{PD} at $V_{CC} = 5 V$ (typ) • Inputs/Outputs Overvoltage Tolerant up to 5.5 V XX M • IOFF Supports Partial Power Down Protection • Source/Sink 24 mA at 3.0 V ЦЦЦ Available in US8, UDFN8 and UQFN8 Packages **NLV Prefix** • Chip Complexity < 100 FETs • NLV Prefix for Automotive and Other Applications Requiring UDFN8, 1.45x1.0 Unique Site and Control Change Requirements; AEC-Q100 **MU3 SUFFIX** ΧМ Qualified and PPAP Capable CASE 517BZ 1 • These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant UDFN8, 1.95x1.0 **MU1 SUFFIX** ΧМ CASE 517CA l٥ 1 A1 = 1 Y1 B1 UQFN8, 1.4x1.2 XM A2 **MQ2 SUFFIX** = 1 Y2 1 B2 CASE 523AS Figure 1. Logic Symbol 10 UQFN8, 1.6x1.6 XX M= **MQ1 SUFFIX** CASE 523AN

X, XX, XXXX = Specific Device Code

= Lot Code

= Year Code

= Week Code

= Date Code = Pb-Free Package

ORDERING INFORMATION See detailed ordering, marking and shipping information in the package dimensions section on page 6 of this data sheet.

= Assembly Location

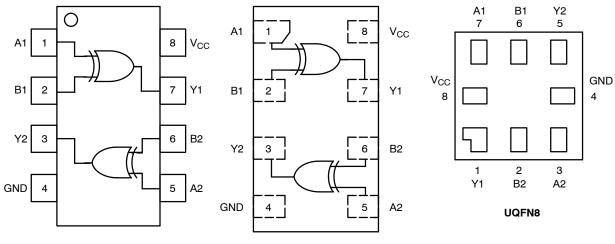
А

L

Y W

Μ

1



US8

UDFN8

Figure 2. Pinout

PIN ASSIGNMENT (US8 / UDFN8)

Pin	Function
1	A1
2	B1
3	Y2
4	GND
5	A2
6	B2
7	Y1
8	V _{CC}

PIN ASSIGNMENT (UQFN8)

Pin	Function
1	Y1
2	B2
3	A2
4	GND
5	Y2
6	B1
7	A1
8	V _{CC}

FUNCTION TABLE

Inp	Output	
Α	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	L

H = HIGH Logic Level L = LOW Logic Level

MAXIMUM RATINGS

Symbol	Characteris	tics	Value	Unit
V _{CC}	DC Supply Voltage	NLV	-0.5 to +7.0 -0.5 to +6.5	V
V _{IN}	DC Input Voltage	NLV	−0.5 to +7.0 −0.5 to +6.5	V
V _{OUT}	DC Output Voltage (NLV)	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +7.0 -0.5 to +7.0	V
	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V _{CC} = 0 V)	-0.5 to V _{CC} + 0.5 -0.5 to +6.5 -0.5 to +6.5	V
I _{IK}	DC Input Diode Current	V _{IN} < GND	-50	mA
I _{OK}	DC Output Diode Current	-50	mA	
I _{OUT}	DC Output Source/Sink Current	±50	mA	
I_{CC} or I_{GND}	DC Supply Current per Supply Pin or Ground	±100	mA	
T _{STG}	Storage Temperature Range		-65 to +150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 s	ecs	260	°C
TJ	Junction Temperature Under Bias		+150	°C
θ_{JA}	Thermal Resistance (Note 2)	US8 UQFN8 UDFN8	250 210 231	°C/W
PD	Power Dissipation in Still Air US8 UQFN8 UDFN8		500 595 541	mW
MSL	Moisture Sensitivity		Level 1	-
F _R	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-
V_{ESD}	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	2000 1000	V
I _{Latchup}	Latchup Performance (Note 4)		±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.

 Applicable to devices with outputs that hidy be in-stated.
 Measured with minimum pad spacing on an FR4 board, using 10mm-by-1inch, 2 ounce copper trace no air flow per JESD51-7.
 HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22–A115–A (Machine Model) be discontinued per JEDEC/JEP172A. 4. Tested to EIA/JESD78 Class II.

RECOMMENDED OPERATING CONDITIONS

Symbol	Characteristics	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage	1.65	5.5	V
V _{IN}	DC Input Voltage	0	5.5	V
V _{OUT}	Tri	e (High or Low State) 0 -State Mode (Note 1) 0 wn Mode (V _{CC} = 0 V) 0	V _{CC} 5.5 5.5	
T _A	Operating Temperature Range	-55	+125	°C
t _r , t _f	Input Rise and Fall Time V	$\begin{array}{c} {}_{CC} = 1.65 \ V \ to \ 1.95 \ V \\ V_{CC} = 2.3 \ V \ to \ 2.7 \ V \\ V_{CC} = 3.0 \ V \ to \ 3.6 \ V \\ V_{CC} = 4.5 \ V \ to \ 5.5 \ V \end{array} \qquad 0$	20 20 10 5	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

	Parameter		Vcc		م = 25°	C	–55°C ≤ T	_A ≤ 125°C	
Symbol		Condition	(V)	Min	Тур	Max	Min	Max	Units
VIH	High-Level Input		1.65 to 1.95	$0.75 \times V_{CC}$			$0.75 \times V_{CC}$		V
	Voltage (NLV)		2.3 to 5.5	0.70 x V _{CC}			$0.70 \times V_{CC}$		
	High-Level Input		1.65 to 1.95	$0.65 \times V_{CC}$			$0.65 \times V_{CC}$		V
	Voltage		2.3 to 5.5	0.70 x V _{CC}			$0.70 \times V_{CC}$		
V _{IL}	Low-Level Input		1.65 to 1.95			0.25 x V _{CC}		0.25 x V _{CC}	V
	Voltage (NLV)		2.3 to 5.5			$0.30 \times V_{CC}$		0.30 x V _{CC}	
	Low-Level Input		1.65 to 1.95			$0.35 \times V_{CC}$		0.35 x V _{CC}	V
	Voltage		2.3 to 5.5			$0.30 \times V_{CC}$		0.30 x V _{CC}	
V _{OH}	High-Level Output Voltage	$ \begin{array}{l} V_{IN} = V_{IH} \mbox{ or } V_{IL} \\ I_{OH} = -100 \ \mu A \\ I_{OH} = -4 \ m A \\ I_{OH} = -8 \ m A \\ I_{OH} = -12 \ m A \\ I_{OH} = -16 \ m A \\ I_{OH} = -24 \ m A \\ I_{OH} = -32 \ m A \end{array} $	1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5	V _{CC} - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	V _{CC} 1.4 2.1 2.4 2.7 2.5 4.0	- - - - - -	V _{CC} - 0.1 1.29 1.9 2.2 2.4 2.3 3.8	- - - - - -	V
V _{OL}	Low-Level Output Voltage		1.65 to 5.5 1.65 2.3 2.7 3.0 3.0 4.5		- 0.08 0.2 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55		0.1 0.24 0.3 0.4 0.4 0.55 0.55	V
I _{IN}	Input Leakage Current	$V_{IN} = 5.5 \text{ V or GND}$	1.65 to 5.5	-	-	±0.1	-	±1.0	μA
I _{OFF}	Power Off Leakage Current	V _{IN} = 5.5 V or V _{OUT} = 5.5 V	0	-	I	1.0	_	10	μA
I _{CC}	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	5.5	-	I	1.0	_	10	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS

					r _A = 25°C)	T _A = -55	to 125°C	
Symbol	Parameter	V _{CC} (V)	Test Conditions	Min	Тур	Max	Min	Max	Units
t _{PLH} ,	Propagation Delay,	1.65 to 1.95	C _L = 15 pF	-	7.9	9.0	-	10.5	ns
t _{PHL}	(A or B) to Y	2.3 to 2.7	R _L = 1 MΩ R ₁ = Open	-	4.1	7.0	-	7.5	
		3.0 to 3.6		-	3.0	4.8	-	5.2	
		4.5 to 5.5		-	2.2	3.5	-	3.8	
		3.0 to 3.6	$C_{L} = 50 \text{ pF},$	-	3.8	5.4	-	5.9	
		4.5 to 5.5	$R_L = 500 \Omega$, $R_1 = Open$	-	2.9	4.2	_	4.6	

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Units
C _{IN}	Input Capacitance	V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	2.5	pF
C _{OUT}	Output Capacitance	V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	2.5	pF
C _{PD}	Power Dissipation Capacitance (Note 5)	10 MHz, V_{CC} = 3.3 V, V_{IN} = 0 V or V_{CC} 10 MHz, V_{CC} = 5.5 V, V_{IN} = 0 V or V_{CC}	9 11	pF

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$. C_{PD} is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

Test

t_{PLH} / t_{PHL}

t_{PLZ} / t_{PZL}

Switch

Position

Open

 $2 \times V_{CC}$

 R_L, Ω

500

500

 C_L, pF

50

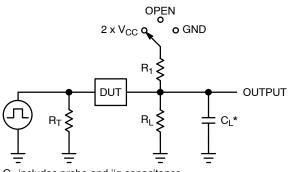
50

See AC Characteristics Table

 R_1, Ω

500

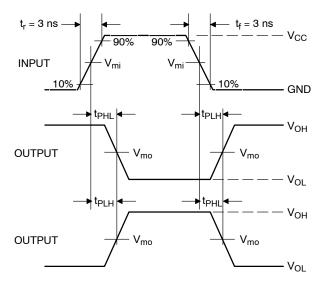
500



GND t_{PHZ} / t_{PZH} X = Don't Care

 C_{L} includes probe and jig capacitance R_T is Z_{OUT} of pulse generator (typically 50 Ω) f = 1 MHz

Figure 3. Test Circuit



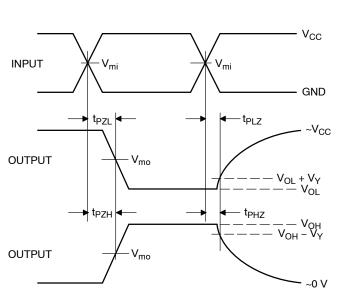


Figure 4. Switching Waveforms

		Vm		
V _{CC} , V	V _{mi} , V	t _{PLH} , t _{PHL}	t _{PZL} , t _{PLZ} , t _{PZH} , t _{PHZ}	V _Y , V
1.65 to 1.95	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.15
2.3 to 2.7	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.15
3.0 to 3.6	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.3
4.5 to 5.5	V _{CC} /2	V _{CC} /2	V _{CC} /2	0.3

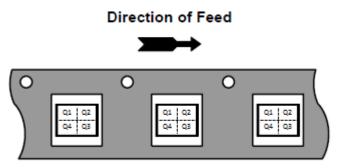
DEVICE ORDERING INFORMATION

Device	Packages	Specific Device Code	Pin 1 Orientation (See below)	Shipping [†]
NL27WZ86USG	US8	L8	Q4	3000 / Tape & Reel
NLV27WZ86USG*	US8	L8	Q4	3000 / Tape & Reel
NL27WZ86MQ1TCG	UQFN8, 1.6 x 1.6, 0.5P	AC	Q1	3000 / Tape & Reel
NL27WZ86MU1TCG (In Development)	UDFN8, 1.95 x 1.0, 0.5P	TBD	TBD	3000 / Tape & Reel
NL27WZ86MU3TCG (In Development)	UDFN8, 1.45 x 1.0, 0.35P	TBD	TBD	3000 / Tape & Reel
NL27WZ86MQT2CG (In Development)	UQFN8, 1.4 x 1.2, 0.4P	TBD	TBD	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

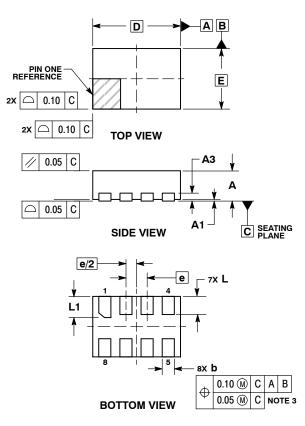
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

Pin 1 Orientation in Tape and Reel



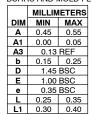
PACKAGE DIMENSIONS

UDFN8, 1.45x1, 0.35P CASE 517BZ ISSUE O

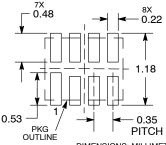


NOTES: 1. DIMENSIONING AND TOLERANCING PER

- Simerosioning and Doleranding FER ASME V14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN
- 0.15 AND 0.20 MM FROM TERMINAL TIP. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH. 4



RECOMMENDED SOLDERING FOOTPRINT*

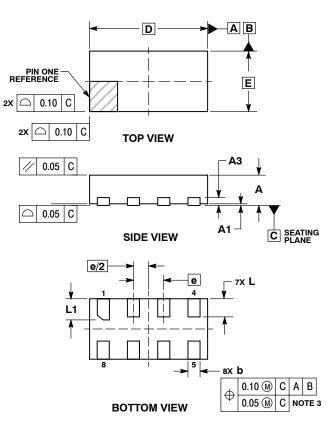


DIMENSIONS: MILLIMETERS *For additional information on our Pb-Free strategy and soldering

details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

UDFN8, 1.95x1, 0.5P CASE 517CA ISSUE O

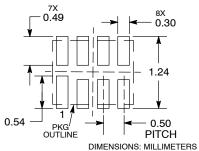


NOTES:

- NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION b APPLIES TO PLATED TERMINAL AND 19 MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 PACKAGE DIMENSIONS EXCLUSIVE OF BUIDES AND MOL D ELASH ASH.

BURRS AND MOLD FL					
	MILLIMETERS				
DIM	MIN	MAX			
Α	0.45	0.55			
A1	0.00	0.05			
A3	0.13	0.13 REF			
b	0.15	0.25			
D	1.95	BSC			
Е	1.00	BSC			
е	0.50	BSC			
L	0.25 0.35				
L1	0.30	0.40			
	DIM A A1 A3 b D E e	MILLIN DIM MIN A 0.45 A1 0.00 A3 0.13 b 0.15 D 1.95 E 1.00 e 0.50 L 0.25	MILLIMETERS MIN MAX A 0.45 0.55 A1 0.00 0.05 A3 0.13 REF b 0.15 0.25 D 1.95 BSC E 1.00 BSC e 0.50 BSC L 0.25 0.35		

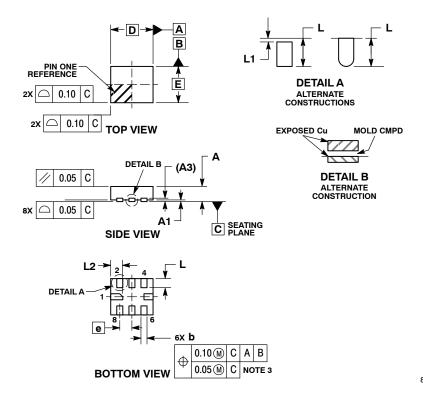
RECOMMENDED **SOLDERING FOOTPRINT***



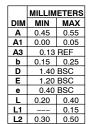
*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

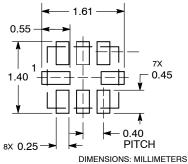
UQFN8, 1.4x1.2, 0.4P CASE 523AS **ISSUE A**



NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.25 mm FROM THE TERMINAL TIP.



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DATE 01 SEP 2021

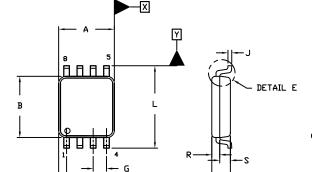


SCALE 4:1

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SEATING PLANE



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0.10 (0.004) T

t_v

DETAIL E

NOTES:

US8 **CASE 493 ISSUE F**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

2. CONTROLLING DIMENSION: MILLIMETERS

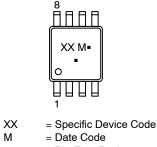
R 0.10 TYP

- DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSION, З. OR GATE BURR. MOLD FLASH, PROTRUSION, OR GATE BURR SHALL NOT EXCEED 0.14 (0.0055') PER SIDE.
- DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH AND PROTRUSION SHALL NOT 4. EXCEED 0.14 (0.0055") PER SIDE.
- LEAD FINISH IS SOLDER PLATING WITH THICKNESS OF 5. 0.0076-0.0203 MM (0.003-0.008").

ALL TOLERANCE UNLESS OTHERWISE SPECIFIED ±0.0508 MM (0.002"). 6.

	MILLIMETERS		INC	HES
DIM	MIN.	MAX.	MIN.	MAX.
Α	1.90	2.10	0.075	0.083
В	2.20	2.40	0.087	0.094
С	0.60	0.90	0.024	0.035
D	0.17	0.25	0.007	0.010
F	0.20	0.35	0.008	0.014
G	0.50	BSC	0.020	BSC
н	0.40	REF	0.016	REF
J	0.10	0.18	0.004	0.007
к	0.00	0.10	0.000	0.004
L	3.00	3.25	0.118	0.128
м	0*	6*	0*	6*
N	0*	10*	0*	10*
Р	0.23	0.34	0.010	0.013
R	0.23	0.33	0.009	0.013
S	0.37	0.47	0.015	0.019
U	0.60	0.80	0.024	0.031
V	0.12	BSC	0.005	BSC

GENERIC **MARKING DIAGRAM***



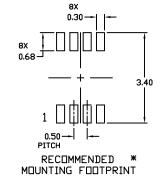
= Pb-Free Package

(Note: Microdot may be in either location)

Μ

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

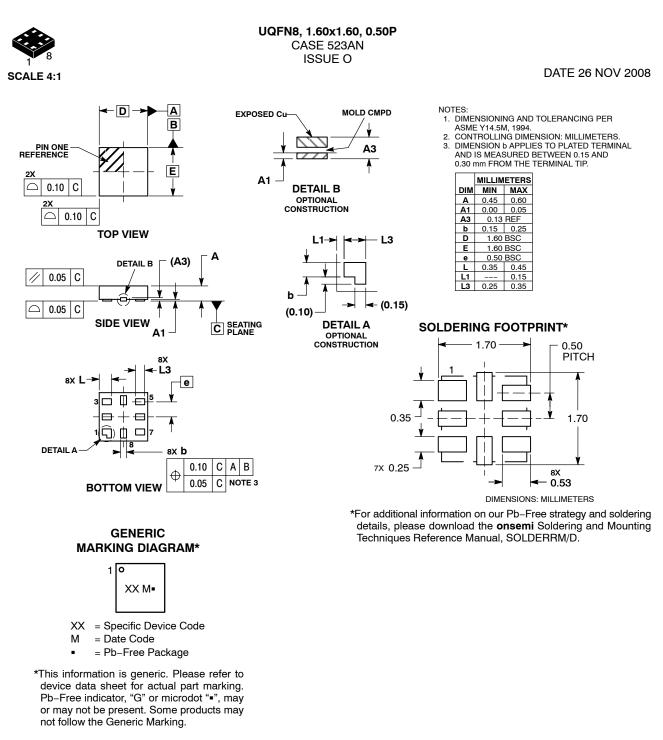
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